

## **A Highly Controllable Electrochemical Anodization Process to Fabricate Porous Anodic Aluminum Oxide Membranes**

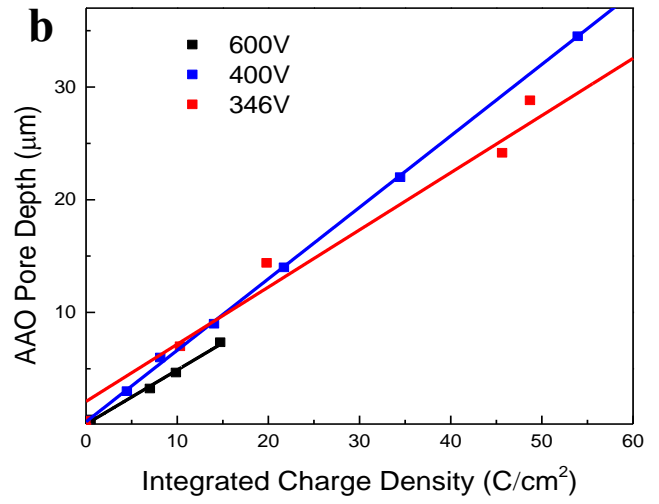
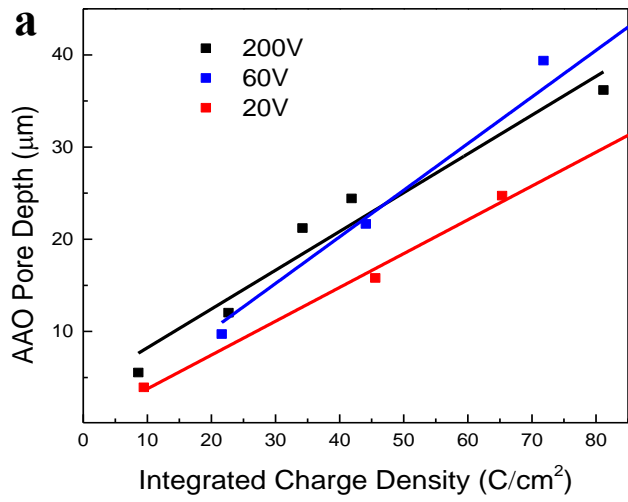
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**Figure S1.** Linear correlation between AAO pore depth and integrated charge density in a large voltage range (a) 20-200 V; (b) 346V-600 V.